# Dual High Voltage TMBS<sup>®</sup> (Trench MOS Barrier Schottky) Rectifier

Ultra Low  $V_F = 0.37$  V at  $I_F = 5$  A

### **FEATURES**

- Trench MOS Schottky technology
- · Low forward voltage drop, low power losses
- · High efficiency operation
- HALOGEN • Solder bath temperature 275 °C maximum, 10 s, FREE per JESD 22-B106

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· Material categorization: for definitions of compliance please see www.vishay.com/doc?99912

### **TYPICAL APPLICATIONS**

For use in high frequency converters, switching power supplies, freewheeling diodes, OR-ing diode, DC/DC converters, and reverse battery protection.

### **MECHANICAL DATA**

Case: TO-220AB

Molding compound meets UL 94 V-0 flammability rating Base P/N-M3 - halogen-free, RoHS-compliant, and commercial grade

Terminals: matte tin plated leads, solderable per J-STD-002 and JESD 22-B102

M3 suffix meets JESD 201 class 1A whisker test

Polarity: as marked

Mounting Torque: 10 in-lbs maximum

<b>MAXIMUM RATINGS</b> (T <sub>A</sub> = 25 °C unless otherwise noted)					
PARAMETER		SYMBOL	V61M103C	UNIT	
Maximum repetitive peak reverse voltage		V <sub>RRM</sub>	100	V	
Maximum average forward rectified current (fig. 1)	per device	I	60	A	
	per diode	IF(AV)	30		
Peak forward surge current 8.3 ms single half sine-wave on rated load per diode	e superimposed	I <sub>FSM</sub>	320	A	
Operating junction temperature range		T <sub>J</sub> <sup>(1)</sup>	-40 to +175	℃	
Storage temperature range		T <sub>STG</sub>	-55 to +175	C	

Note

<sup>(1)</sup> The heat generated must be less than the thermal conductivity from junction to ambient:  $dP_D/dT_J < 1/R_{0,JA}$ 

2 x 30 A

100 V

320 A

0.63 V

175 °C

TO-220AB

Common cathode



**PRIMARY CHARACTERISTICS** 

I<sub>F(AV)</sub>

V<sub>RRM</sub>

 $I_{FSM}$ 

V<sub>F</sub> at I<sub>F</sub> = 30 A (125 °C)

T<sub>J</sub> max.

Package

Circuit configuration







# V61M103C

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<b>ELECTRICAL CHARACTERISTICS</b> ( $T_J = 25 \text{ °C}$ unless otherwise noted)						
PARAMETER	TEST CO	NDITIONS	SYMBOL	TYP.	MAX.	UNIT
Instantaneous forward voltage per diode	I <sub>F</sub> = 5 A	T <sub>J</sub> = 25 °C	V <sub>F</sub> <sup>(1)</sup>	0.47	-	V
	I <sub>F</sub> = 15 A			0.58	-	
	I <sub>F</sub> = 30 A			0.71	0.77	
	I <sub>F</sub> = 5 A	T <sub>J</sub> = 125 °C		0.37	-	
	I <sub>F</sub> = 15 A			0.51	-	
	I <sub>F</sub> = 30 A			0.63	0.68	
Reverse current at rated V <sub>R</sub> per diode	V 70.V	T <sub>J</sub> = 25 °C	<sub>R</sub> (2)	0.008	-	mA
	V <sub>R</sub> = 70 V	T <sub>J</sub> = 125 °C		5.2	-	
	V <sub>R</sub> = 100 V	T <sub>J</sub> = 25 °C		-	0.8	
		T <sub>J</sub> = 125 °C		12	30	
Typical junction capacitance	4 V, 1MHz		CJ	3250	-	pF

#### Notes

 $^{(2)}\,$  Pulse test: 300  $\mu s$  pulse width, 1 % duty cycle

<sup>(3)</sup> Pulse test: Pulse width  $\leq$  5 ms

<b>THERMAL CHARACTERISTICS</b> ( $T_A = 25 \text{ °C}$ unless otherwise noted)					
PARAMETER	SYMBOL	V61M103C	UNIT		
Typical thermal resistance per device	R <sub>θJC</sub> <sup>(1)</sup>	1.0	°C/W		

#### Note

<sup>(4)</sup> Thermal resistance junction-to-case to follow JEDEC<sup>®</sup> 51-14 transient dual interface test method (TDIM)

OERDERING INFORMATION (Example)						
PREFERRED P/N	UNIT WEIGHT (g)	PACKAGE CODE	BASE QUANTITY	DELIVERY MODE		
V61M103C-M3/P	1.88	Р	50/tube	Tube		



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## RATINGS AND CHARACTERISTICS CURVES (T<sub>A</sub> = 25 °C unless otherwise noted)

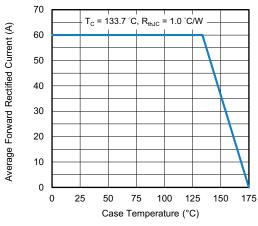


Fig. 1 - Forward Current Derating Curve

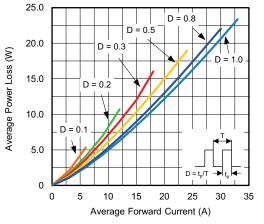


Fig. 2 - Forward Power Loss Characteristics Per Diode

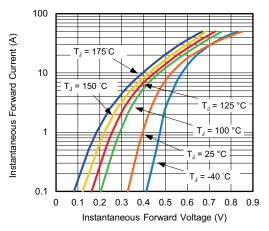


Fig. 3 - Typical Instantaneous Forward Characteristics Per Diode

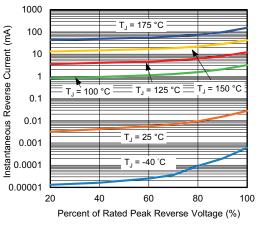


Fig. 4 - Typical Reverse Characteristics Per Diode

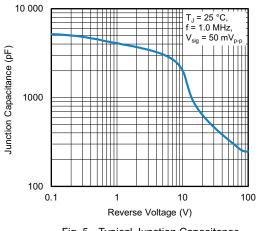
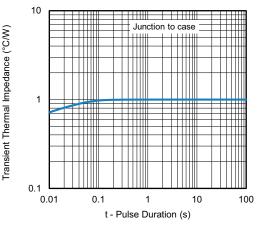


Fig. 5 - Typical Junction Capacitance



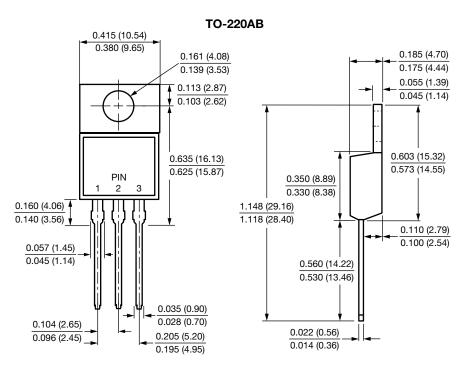


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## **PACKAGE OUTLINE DIMENSIONS** in inches (millimeters)





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